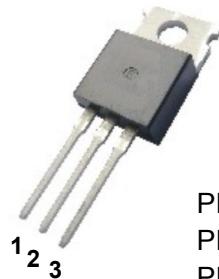


## DESCRIPTION

- With TO-220 package
- Complement to type TIP3055
- 90 W at 25°C case temperature
- 15 A continuous collector current



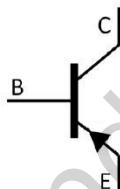
PIN1 : Base  
 PIN 2 : Collector  
 PIN 3 : Emitter

## APPLICATIONS

- Designed for general-purpose switching and amplifier applications.

## PINNING

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter



## Absolute maximum ratings(Ta= )

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V <sub>CBO</sub>	Collector-base voltage	Open emitter	100	V
V <sub>CEO</sub>	Collector-emitter voltage	Open base	60	V
V <sub>EBO</sub>	Emitter-base voltage	Open collector	7	V
I <sub>C</sub>	Collector current		15	A
I <sub>B</sub>	Base current		7	A
P <sub>C</sub>	Collector power dissipation	T <sub>C</sub> =25	90	W
T <sub>j</sub>	Junction temperature		150	
T <sub>stg</sub>	Storage temperature		-65~150	

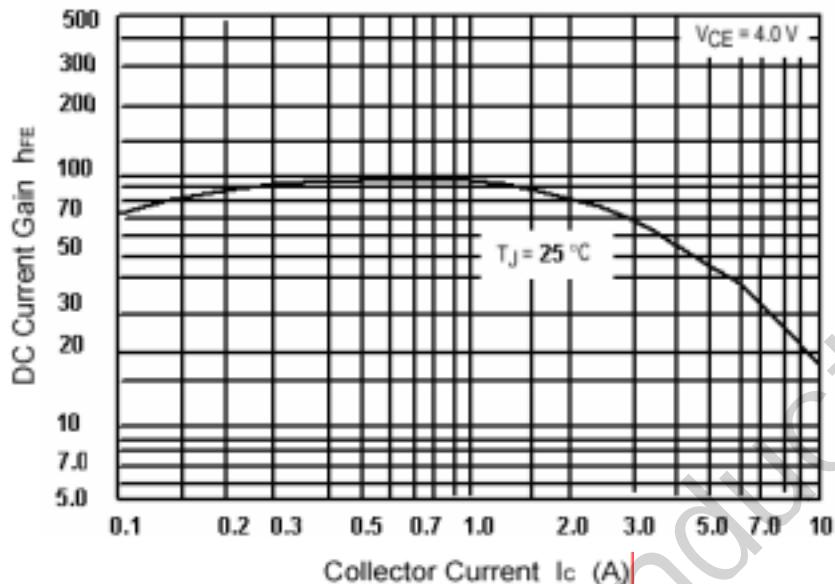
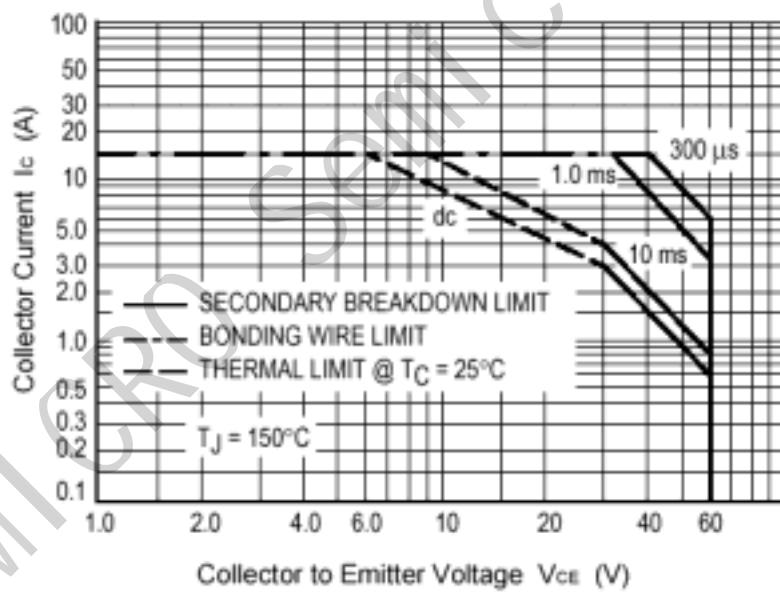
## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R <sub>th j-c</sub>	Thermal resistance junction to case	1.39	/W

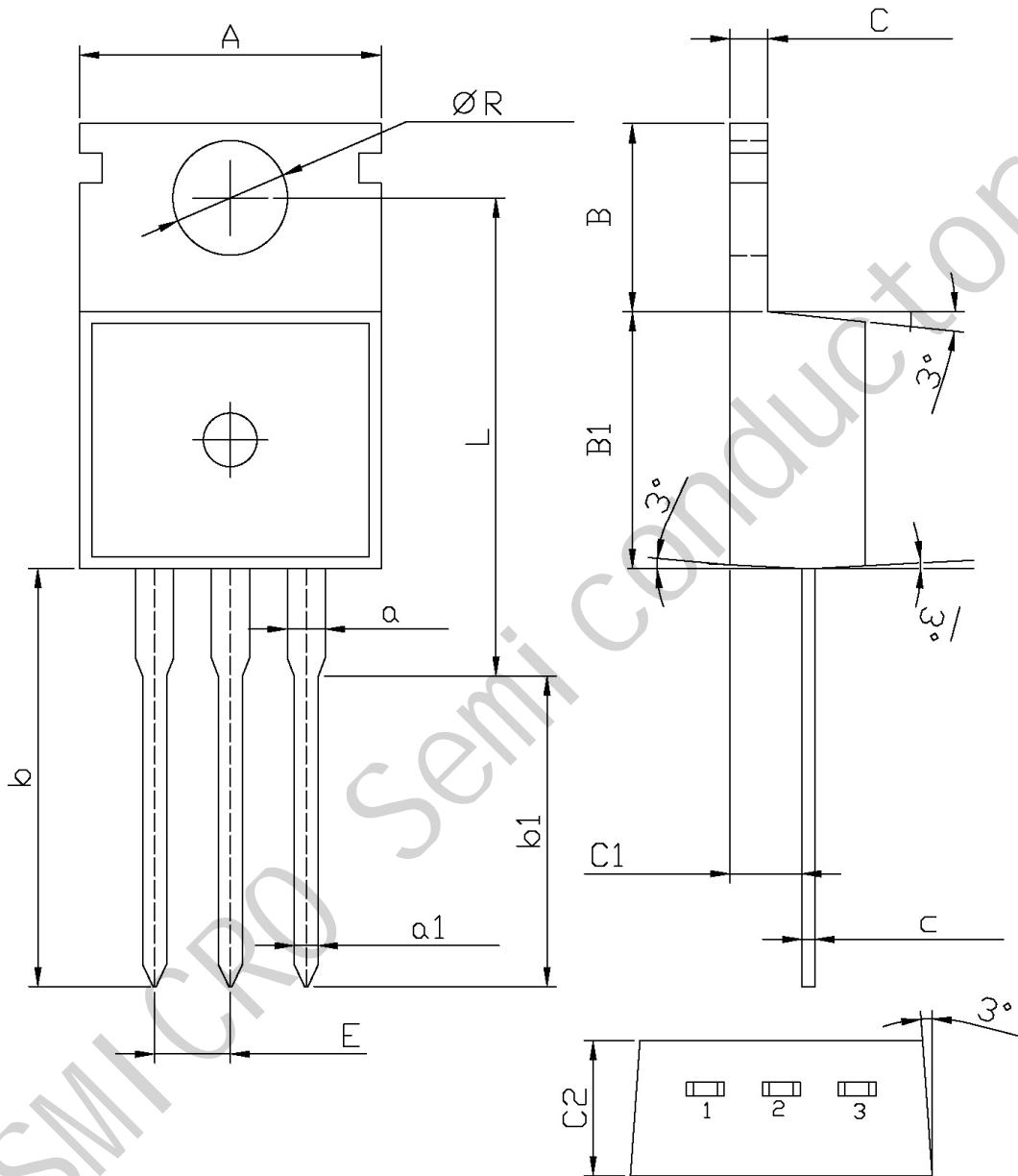
## CHARACTERISTICS

 T<sub>j</sub>=25 unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-emitter sustaining voltage	I <sub>C</sub> =30mA ; I <sub>B</sub> =0	60			V
V <sub>CEsat-1</sub>	Collector-emitter saturation voltage	I <sub>C</sub> =4A; I <sub>B</sub> =0.4A			1.1	V
V <sub>CEsat-2</sub>	Collector-emitter saturation voltage	I <sub>C</sub> =10A ; I <sub>B</sub> =3.3A			3.0	V
V <sub>BE</sub>	Base-emitter on voltage	I <sub>C</sub> =4A ; V <sub>CE</sub> =4V			1.5	V
I <sub>CEO</sub>	Collector cut-off current	V <sub>CE</sub> =30V; I <sub>B</sub> =0			0.7	mA
I <sub>CER</sub>	Collector cut-off current	V <sub>CE</sub> =70Vdc; R <sub>BE</sub> =100Ohm			1.0	mA
I <sub>CEV</sub>	Collector cut-off current	V <sub>CE</sub> =100Vdc, V <sub>BE(off)</sub> =1.5Vdc			5.0	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> =7V; I <sub>C</sub> =0			5.0	mA
h <sub>FE-1</sub>	DC current gain	I <sub>C</sub> =4A ; V <sub>CE</sub> =4V	20		70	
h <sub>FE-2</sub>	DC current gain	I <sub>C</sub> =10A ; V <sub>CE</sub> =4V	5.0			
I <sub>s/b</sub>	Second breakdown collector current With base forward biased	V <sub>CE</sub> =30Vdc, t=1.0s, Nonrepetitive	3.0			A
f <sub>T</sub>	Transition frequency	I <sub>C</sub> =0.5A ; V <sub>CE</sub> =10V	2.5			MHz


**Fig.3 DC current Gain**

**Fig.4 Safe Operating Area**

## PACKAGE OUTLINE



Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
A	9.8	10.2	C	1.2	1.4
R	3.56	3.64	B	6.3	6.7
L	15.7	16.1	B1	9.0	9.4
b	12.6	13.6	C1	2.2	2.6
b1	9.6	10.6	a1	0.7	0.9
a	1.22	1.32	c	0.4	0.6
E	2.34	2.74	C2	4.3	4.7